

(JOINT INVENTORS)  
Any. Docket No.: BUR920010102US1

**Declaration and Power of Attorney for Patent Application**

As a below named inventor, I hereby declare that:

My residence, post office address and citizenship are as stated below next to my name; I believe I am the original, first and sole inventor (if only one name is listed below) or an original, first and joint inventor (if plural names are listed below) of the subject matter which is claimed and for which a patent is sought on the invention entitled:

**FINFET CMOS WITH NVRAM CAPABILITY**

the specification of which (check one)

is attached hereto.

was filed on \_\_\_\_\_ as Application Serial No. \_\_\_\_\_ and was amended on \_\_\_\_\_

I hereby state that I have reviewed and understand the contents of the above-identified specification, including the claims, as amended by any amendment referred to above.

I acknowledge the duty to disclose information which is material to the patentability of this application in accordance with Title 37, Code of Federal Regulations, §1.56.

I hereby claim foreign priority benefits under Title 35, United States Code, §119 (a)-(d) or §365(b) of any foreign application(s) for patent or inventor's certificate listed below and have also identified below any foreign application for patent or inventor's certificate having a filing date before that of the application on which priority is claimed:

Prior Foreign Application(s): Number	Country	Day/Month/Year	Priority Claimed
_____	_____	_____	_____
_____	_____	_____	_____

I hereby claim the benefit under Title 35, United States Code, §120 of any United States application(s) listed below.

Application Number	Filing Date
_____	_____

I hereby claim the benefit under Title 35, United States Code, §120 of any United States application(s) listed below and, insofar as the subject matter of each of the claims of this application is not disclosed in the prior United States application in the manner provided by the first paragraph of Title 35, United States Code, §112, I acknowledge the duty to disclose information material to the patentability of this application as defined in Title

(JOINT INVENTORS)  
Atty. Docket No.: BUR920010102US1

37, Code of Federal Regulations, §1.56 which occurred between the filing date of the prior application and the national or PCT international filing date of this application:

**Prior U.S. Applications:**

Serial No.	Filing Date	Status
_____	_____	_____

I hereby appoint the following attorneys and/or agents to prosecute this application and transact all business in the Patent and Trademark Office connected therewith:

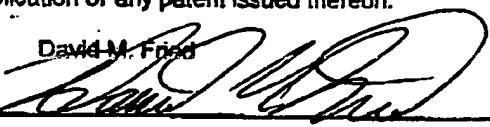
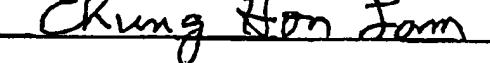
Mark F. Chadurjian Reg. No. 30,739	Richard A. Henkler Reg. No. 39,220	Richard M. Kotulak Reg. No. 27,712	Howard J. Walter, Jr. Reg. No. 24,892
William D. Sabo Reg. No. 27,465	Robert A. Walsh Reg. No. 26,516	Albert L. Schmeiser Reg. No. 30,681	S. Jared Pitts Reg. No. 38,579
Jack P. Friedman Reg. No. 44,688	Allen L. Olsen Reg. No. 37,543	Charles T. Watts Reg. No. 16,564	Keith L. Jenkins Reg. No. 46,303
Anthony M. Palagonia Reg. No. 41,237	Diane E. Smith Reg. No. 40,180	Pacer K. Udall Reg. No. P-50,976	Kenneth A. Nelson Reg. No. 48,677
Kenneth C. Booth Reg. No. 42,342	Susan Sutterfield Wilks Reg. No. 48,192	All attorneys and/or agents at Customer No.: 30607	Joseph C. Redmond Reg. No. 18,753

Send all correspondence to: Customer No.: 30607  
 S. Jared Pitts  
 Schmeiser, Olsen & Watts LLP  
 18 East University Drive, #101  
 Mesa, Arizona 85201

Direct Telephone Calls to: S. Jared Pitts  
 (480) 655-0073

(JOINT INVENTORS)  
Atty. Docket No.: BUR920010102US1

I hereby declare that all statements made herein of my own knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under Section 1001 of Title 18 of the United States Code and that such willful false statements may jeopardize the validity of the application or any patent issued thereon.

(1) Inventor:	David M. Fried		12 March 2002
Signature:			Date
Residence:	201 Maple Avenue Ithaca, NY 14850	Apt B2	
Citizenship:	United States of America		
Post Office Address:	Same as Residence		
(2) Inventor:	Chung Hon Lam		12 March 2002
Signature:			Date
Residence:	61 Aster Lane Williston, VT 05495		
Citizenship:	United States of America		
Post Office Address:	Same as Residence		
(3) Inventor:	Edward J. Nowak		8 March 2002
Signature:			Date
Residence:	8 Windridge Road Essex Junction, VT 05452		
Citizenship:	United States of America		
Post Office Address:	Same as Residence		

**Change Of Attorney Or Agent's Address In Application  
(37 CFR 1.8(a))**

Docket No.

BUR920010102US2

In Re Application Of: Fried et al.

Serial No.	Filing Date	Examiner	Group Art Unit
		Nguyen, Cuong Quang	2811

Invention: FINFET CMOS WITH NVRAM CAPABILITY

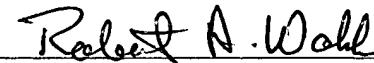
**TO THE ASSISTANT COMMISSIONER FOR PATENTS**

Please send all correspondence for this application to:

**Customer No. 24241**

Please direct all telephone calls to:

**William D. Sabo, (802) 769-9454**



*Signature of Attorney or Agent of Record*

**Robert A. Walsh, Reg. No. 26,516  
IBM Corporation, IPLaw Dept. 972E  
1000 River Street  
Essex Junction, VT 05452**

*Registration Number & Address of Attorney or Agent of Record*

Dated: 9/21/2003

I certify that this document is being deposited on 9/30/03 with the U.S. Postal Service as first class mail under 37 C.F.R. 1.8 and is addressed to the Assistant Commissioner for Patents, Washington, D.C. 20231. EV 024700775 US



*Arnette Dodge*

*Signature of Person Mailing Correspondence*



*Arnette Dodge*

*Typed or Printed Name of Person Mailing Correspondence*